



N-Channel 100 V (D-S) MOSFET

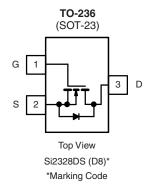
PRODUC	T SUMMARY	
V _{DS} (V)	$R_{DS(on)}(\Omega)$	I _D (A)
100	0.250 at V _{GS} = 10 V	1.5

FEATURES

- Halogen-free According to IEC 61249-2-21
- 100 % R_g and UIS Tested TrenchFET[®] Power MOSFET
- Compliant to RoHS Directive 2002/95/EC







Ordering Information: Si2328DS-T1-E3 (Lead (Pb)-free)

Si2328DS-T1-GE3 (Lead (Pb)-free and Halogen-free)

ABSOLUTE MAXIMUM RATINGS	6 (T _A = 25 °C, unle	ess otherwise	noted)		
Parameter	Symbol	5 s	Steady State	Unit	
Drain-Source Voltage	V _{DS}	100		V	
Gate-Source Voltage	V _{GS}	±			
Continuous Proin Current (T = 150 °C)8	T _A = 25 °C		1.5	1.15	^
Continuous Drain Current (T _J = 150 °C) ^a	T _A = 70 °C	I _D	1.2	0.92	
Pulsed Drain Current ^b		I _{DM}	6		Α
Avalanche Current ^b	L = 0.1 mH	I _{AS}	6		
Single Avalanche Energy	L = 0.1 IIII	E _{AS}	1.8		mJ
Continuous Source Current (Diode Conduction) ^a		I _S	0.6		Α
Power Dissipation ^a	T _A = 25 °C	В	1.25	0.73	W
rower Dissipation:	T _A = 70 °C	P _D	0.80	0.47	VV
Operating Junction and Storage Temperature Range		T _J , T _{stq}	- 55 to 150		°C

THERMAL RESISTANCE RATINGS						
Parameter		Symbol	Typical Maximum		Unit	
Maximum Junction-to-Ambient ^a	t ≤ 5 s	В	80	100		
Maximum Junction-to-Ambient	Steady State	R_{thJA}	130	170	°C/W	
Maximum Junction-to-Foot	Steady State	R _{thJF}	45	55]	

Notes:

- a. Surface mounted on 1" x 1" FR4 board.
- b. Pulse width limited by maximum junction temperature.

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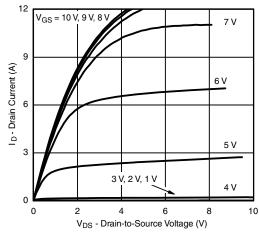
SPECIFICATIONS (T _A = 25 °C, unless otherwise noted)							
			Limits				
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static							
Drain-Source Breakdown Voltage	V_{DS}	$V_{GS} = 0 \text{ V}, I_D = 1 \text{ mA}$	100			V	
Gate-Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = 250 \mu A$	2		4	V	
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			± 100	nA	
Zero Gate Voltage Drain Current	1	$V_{DS} = 100 \text{ V}, V_{GS} = 0 \text{ V}$			1		
Zero Gate Voltage Drain Current	I _{DSS}	V_{DS} = 100 V, V_{GS} = 0 V, T_J = 70 °C			75	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge 15 \text{ V}, V_{GS} = 10 \text{ V}$	6			Α	
Drain-Source On-Resistance ^a	R _{DS(on)}	$V_{GS} = 10 \text{ V}, I_D = 1.5 \text{ A}$		0.195	0.250	Ω	
Forward Transconductance ^a	9 _{fs}	$V_{DS} = 15 \text{ V}, I_D = 1.5 \text{ A}$		4		S	
Diode Forward Voltage	V_{SD}	I _S = 1 A, V _{GS} = 0 V		0.8	1.2	V	
Dynamic ^b							
Total Gate Charge	Q_g			3.3	5		
Gate-Source Charge	Q_{gs}	$V_{DS} = 50 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 1.5 \text{ A}$		0.47		nC	
Gate-Drain Charge	Q _{gd}			1.45			
Gate Resistance	R_g		0.5	1.3	2.4	Ω	
Switching							
Turn-On Delay Time	t _{d(on)}			7	11		
Rise Time	t _r	V_{DD} = 50 V, R_L = 33 Ω		11	17		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong 0.2 \text{ Å}, V_{GEN} = 10 \text{ V}, R_g = 6 \Omega$		9	15	ns	
Fall Time	t _f			10	15		
Source-Drain Reverse Recovery Time	t _{rr}	I _F = 1.5 A, dI/dt = 100 A/μs		50	100		

Notes:

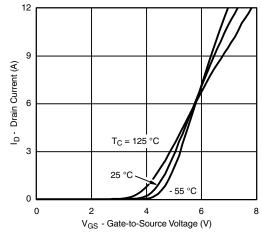
- a. Pulse test: PW \leq 300 $\mu s,$ duty cycle \leq 2 %.
- b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



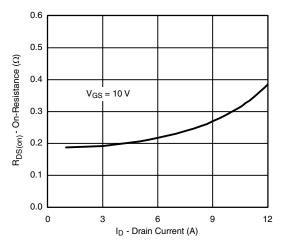




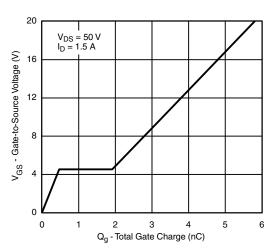
Transfer Characteristics



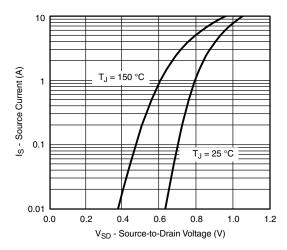
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)



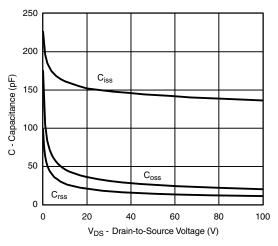
On-Resistance vs. Drain Current



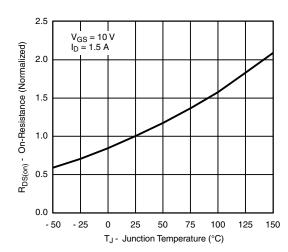
Gate Charge



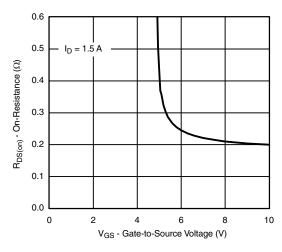
Source-Drain Diode Forward Voltage



Capacitance



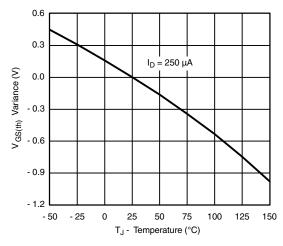
On-Resistance vs. Junction Temperature

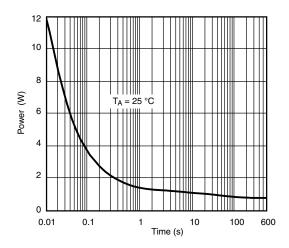


On-Resistance vs. Gate-to-Source Voltage

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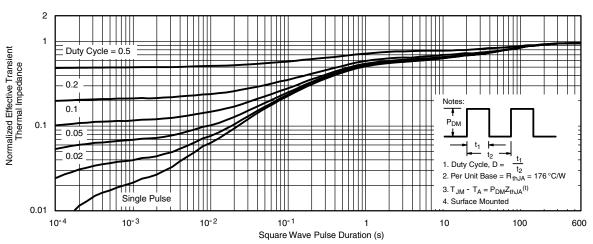
TYPICAL CHARACTERISTICS (25 °C, unless otherwise noted)





Threshold Voltage

Single Pulse Power

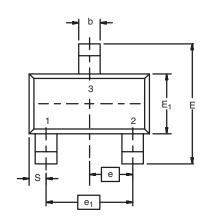


Normalized Thermal Transient Impedance, Junction-to-Ambient

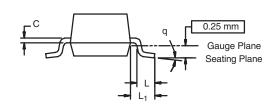
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SOT-23 (TO-236): 3-LEAD







Dim	MILLIN	IETERS	INCHES			
Dim	Min	Max	Min	Max		
Α	0.89	1.12	0.035	0.044		
A ₁	0.01	0.10	0.0004	0.004		
A ₂	0.88	1.02	0.0346	0.040		
b	0.35	0.50	0.014	0.020		
С	0.085	0.18	0.003	0.007		
D	2.80	3.04	0.110	0.120		
E	2.10	2.64	0.083	0.104		
E ₁	1.20	1.40	0.047	0.055		
е	0.95	0.95 BSC		0.0374 Ref		
e ₁	1.90 BSC		0.0748 Ref			
L	0.40	0.60	0.016	0.024		
L ₁	0.64 Ref		0.025 Ref			
S	0.50 Ref		0.020 Ref			
q	3°	8°	3°	8°		
ECN: S-03946-Rev. K. 09-	Jul-01					

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RECOMMENDED MINIMUM PADS FOR SOT-23



Recommended Minimum Pads Dimensions in Inches/(mm)

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APPLICATION NOTE

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